

# CHENMKO ENTERPRISE CO.,LTD

STVJ+"\$AGP-A

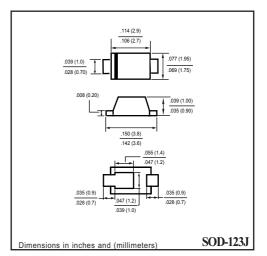
Halogens free devices GLASS PASSIVATED JUNCTION TRANSIENT VOLTAGE SUPPRESSOR

VOLTAGE-Ï VOLTS

225 WATTS PEAK POWER 1.0 WATT STEADY STATE

- Plastic package
- 225W surge capability at 1ms
- Glass passivated chip junction in SOD-123J Package
- Excellent clamping capability
  Low Zener Impedance
- Fast response time: typically less than 1.0ps from 0 volts to BV min.
- Typical IR less than 1 uA above 10V
- High temperature soldering guaranteed : 260°C/10 seconds at terminals





## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

### **DEVICES FOR BIDIRECTIONAL APPLICATIONS**

For Bidirectional use C or CA Suffix for types STVJ5.0AGP-A thru types STVJ51AGP-A Electrical characteristics apply in both directions.

### **MAXIMUM RATINGES** ( At TA = $25^{\circ}$ C unless otherwise noted )

RATINGS	SYMBOL	VALUE	UNITS
Peak Power Dissipation at TA = 25°C, Tp = 1ms ( Note1 )	Ррк	Minimum 225	Watts
Steady State Power Dissipation at TL = 25°C	PD	1.0	Watts
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load ( Note 2 )	IFSM	50	Amps
Operating and Storage Temperature Range	TJ, TSTG	-65 to +175	°C

NOTES: 1. Non-repetitive current pulse, per Fig. 3 and derated above TA = 25°C per Fig. 2.

- 2. 8.3ms single half sine-wave, duty cycle = 4 pulses per minute maximum.
- 3. PC Board Mounted on 0.2 X 0.2" ( 5 X 5mm ) copper pad area

2008-07

# ELECTRICAL CHARACTERISTICS ( STVJ7.0AGP-A )

ТҮРЕ	Zener Voltage VZ (V) @ IZT		Test current	Working Peak Reverse	Maximum Reverse Leakage	Maximum Reverse	Maximum reverse Voltage	
	Min	Nom	Max		Voltage	Current	Current	@Irsm
	Volts	Volts	Volts	Izt(mA)	Vrwm(V)	IR(uA)	Irsm(A)	Vrsm(V)
STVJ7.0AGP-A	7.78		8.6	10	7	100	12	18.8

